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Nuclear Instruments and Methods in Physics Research B 117 (1996) 477–484

NIM B
Beam Interactions with Materials & Atoms

Author index

Abriola, D., see Fernández Niello, J.O. 117 (1996) 156
Aganyants, A.O., V.B. Gharibyan and Yu.A. Vartanov, Polarization of photon and electron beams by means of an oriented monocyrstal 117 (1996) 205
Ali, Y.P., A.M. Narsale, U. Bhambhani, A. Damle, V.P. Salvi, B.M. Arora, A.P. Shah and D. Kanjilal, Electrical characteristics of GaAs implanted with 70 MeV ^{120}Sn ions 117 (1996) 129
Alvarez, D.E., see Fernández Niello, J.O. 117 (1996) 156
Alvarez, I., see Cisneros, C. 117 (1996) 1
Andler, G., see Asp, S. 117 (1996) 31
Andrade I., E., see Barragán-Vidal, A. 117 (1996) 304
Andrews, H.R., see Cornett, R.J. 117 (1996) 436
Angelone, M., M. Chiti and A. Esposito, Measurement of supralinearity factor of CaF_2 : Tm (TLD-300) thermoluminescent dosimeter 117 (1996) 428
Ärje, J., see Koivisto, H. 117 (1996) 186
Arokiaraj, J., see Arulkumaran, S. 117 (1996) 243
Arora, B.M., see Ali, Y.P. 117 (1996) 129
Arulkumaran, S., J. Arokiaraj, M. Udhayasankar, J. Kumar and D. Kanjilal, Electrical characteristics of 100 MeV ^{28}Si implanted LEC grown GaAs⟨100⟩ 117 (1996) 243
Asp, S., R. Schuch, D.R. DeWitt, C. Biedermann, H. Gao, W. Zong, G. Andler and E. Justiniano, Laser-induced recombination of D^+ 117 (1996) 31
Assmann, W., see Hartmann, J. 117 (1996) 392
Asubiojo, O.I., see Ojo, J.O. 117 (1996) 175

Bachmann, T., see Schulz, R. 117 (1996) 207
Bajt, S., see Zappalà, A. 117 (1996) 145
Banks, J.C., see Pedersen, D. 117 (1996) 170
Barbier, D., see Erramli, H. 117 (1996) 283
Barragán-Vidal, A., F. García-Santibáñez, G. Murillo, E. Andrade I. and M. Feregrino-Dorantes, Analysis of a very rough sample by accelerator techniques 117 (1996) 304
Baudin, K., A. Brunelle, S. Della-Negra, J. Depauw, Y. Le Beyec and E.S. Parilis, Sublinear effect in electron emission from solids bombarded with swift gold clusters 117 (1996) 47
Benka, O., M. Pfaffenlehner and A. Schinner, Electron emission yield of Al, Cu and Au targets induced by fast hydrogen and helium ions 117 (1996) 350
Bergmann, U., see Masciovecchio, C. 117 (1996) 339
Bertrand, P., see Delcorte, A. 117 (1996) 235
Bertschy, M., J. Jolie and W. Mondelaers, A tunable monochromatic gamma-ray source. Part 4. The FCMT operation mode 117 (1996) 333
Bethge, K., see Prigge, U. 117 (1996) 18
Bethge, K., see Vollmer, M. 117 (1996) 21
Betz, G., see Kornich, G.V. 117 (1996) 81
Betzl, M., see Dobler, M. 117 (1996) 117
Bhambhani, U., see Ali, Y.P. 117 (1996) 129
Biedermann, C., see Asp, S. 117 (1996) 31
Biryukov, V., Computer simulation of the energy loss spectra in bent crystals 117 (1996) 357
Biryukov, V., Optimization of crystal extraction experiment 117 (1996) 463
Bischoff, L., see Schneider, P. 117 (1996) 77
Blinov, A., see Stan-Sion, C. 117 (1996) 26
Blondiaux, G., see Erramli, H. 117 (1996) 283
Bonifazzi, C., see Tartari, A. 117 (1996) 325
Boudinov, H., see de Souza, J.P. 117 (1996) 403
Brissaud, I., G. Lagarde and P. Midy, Study of multilayers by PIXE technique. Application to paintings 117 (1996) 179

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Brunelle, A., see Baudin, K. 117 (1996) 47
Brunelle, A., see Tomaschko, Ch. 117 (1996) 90
Busnengo, H.F., see Corchs, S.E. 117 (1996) 41

Calderin, L. and J.J. Diaz, A new iterative method for deconvolution of Doppler broadened lineshapes of positron annihilation γ-ray spectra 117 (1996) 457
Capurro, O.A., see Fernández Niello, J.O. 117 (1996) 156
Cardon, F., see Everaert, J.L. 117 (1996) 397
Casnati, E., see Tartari, A. 117 (1996) 325
Chadderton, L.T., see Fink, D. 117 (1996) 134
Chadderton, L.T. and E.G. Gamaly, Fullerene genesis by ion beams II: Disclinations and the corranulene road 117 (1996) 375
Chae, K.H., Y.S. Lee, C.N. Whang, Y. Jeon, B.S. Choi and M. Croft, Charge redistribution in ion-beam-mixed Pd–Ag alloys 117 (1996) 123
Chant, L., see Cornett, R.J. 117 (1996) 436
Chaput, T., see Cornett, R.J. 117 (1996) 436
Chen, B.L., see Wang, W.J. 117 (1996) 140
Chiang, C.I., O. Meyer and R.M.C. da Silva, The modification of mechanical properties and adhesion of boron carbide sputtered films by ion implantation 117 (1996) 408
Chiti, M., see Angelone, M. 117 (1996) 428
Cho, W.S., see Kim, K.S. 117 (1996) 289
Choi, B.S., see Chae, K.H. 117 (1996) 123
Choi, D.S., see Kim, K.S. 117 (1996) 289
Christofides, C., see Othonos, A. 117 (1996) 367
Cisneros, C., H. Martínez, B.E. Fuentes, I. Alvarez, J. de Urquijo and I. Dominguez, Single electron capture of H^+ in Mg in the energy range 0.5 to 5.0 keV 117 (1996) 1
Clacher, A.P., see Fifield, L.K. 117 (1996) 295
Colla, T.J. and H.M. Urbassek, Influence of adatom coverage on sputter yield 117 (1996) 361
Corchs, S.E., H.F. Busnengo, R.D. Rivarola and J.H. McGuire, Interference effects in collisions between heavy ions and molecular targets 117 (1996) 41
Cornett, R.J., H.R. Andrews, L. Chant, T. Chaput, Y. Imahori, J. Jirovec, S. Kramer, V.T. Koslowsky, G.M. Milton and J.C.D. Milton, High temperature pyrolysis to extract ^{36}Cl for Accelerator Mass Spectrometry measurements . 117 (1996) 436
Cresswell, R.G., see Fifield, L.K. 117 (1996) 295
Croft, M., see Chae, K.H. 117 (1996) 123
Cucinotta, F.A., see Tripathi, R.K. 117 (1996) 347

Dabek, J.T., see Kupila-Rantala, T. 117 (1996) 320
Damle, A., see Ali, Y.P. 117 (1996) 129
Da Silva, R.M.C., see Chiang, C.I. 117 (1996) 408
Davies, G.J., see Lally, C.H. 117 (1996) 421
Day, J.P., see Fifield, L.K. 117 (1996) 295
Delcorte, A. and P. Bertrand, Energy distributions of hydrocarbon secondary ions from thin organic films under keV ion bombardment: Correlation between kinetic and formation energy of ions sputtered from tricosenoic acid 117 (1996) 235
Della-Negra, S., see Baudin, K. 117 (1996) 47
Della-Negra, S., see Tomaschko, Ch. 117 (1996) 90
Depauw, J., see Baudin, K. 117 (1996) 47
De Souza, J.P., H. Boudinov and J.W. Swart, Rapid thermal annealing of Mg^+ and P^+ co-implanted GaAs 117 (1996) 403
De Urquijo, J., see Cisneros, C. 117 (1996) 1
DeWitt, D.R., see Asp, S. 117 (1996) 31
Dhal, B.B., H.C. Padhi and D. Trautmann, A strange projectile dependence of L_2-subshell ionization cross section of Au for ^{28}Si and ^{32}S ion bombardment 117 (1996) 218
Diaz, J.J., see Calderin, L. 117 (1996) 457
Di Tada, M., see Fernández Niello, J.O. 117 (1996) 156
Di Tada, M.L., see Fifield, L.K. 117 (1996) 295
Dobler, M., H. Reuther, M. Betzl, M. Mäder and W. Möller, Investigations of ion implanted iron silicide layers after annealing and irradiation 117 (1996) 117
Dominguez, I., see Cisneros, C. 117 (1996) 1
Dubovskaya, I.Ya., see Stepanov, S.A. 117 (1996) 55
Dumitru, M., see Stan-Sion, C. 117 (1996) 26
Durosinmi, M.A., see Ojo, J.O. 117 (1996) 175
Du Yuan-Cheng, see Ren Zhong-Min 117 (1996) 249

Ensinger, W., see Hartmann, J. 117 (1996) 392
Erramli, H., M.A. Misdaq, G. Blondiaux, C. Maddalon-Vinante and D. Barbier, Study of the oxygen behaviour in thermally treated Czochralski silicon by combining CPAA with ion channeling 117 (1996) 283
Esposito, A., see Angelone, M. 117 (1996) 428
Etchegoyen, A., see Fernández Niello, J.O. 117 (1996) 156
Everaert, J.L., F. Verhaegen, R.L. Van Meirhaeghe, J. Uyttenhove and F. Cardon, Quantitative prediction of acceptor concentration reduction in boron doped silicon due to electron irradiation 117 (1996) 397

Fabricius, N., see Gießler, K.-H. 117 (1996) 447
Felsteiner, J., see Tartari, A. 117 (1996) 325
Feregrino-Dorantes, M., see Barragán-Vidal, A. 117 (1996) 304
Fernández Niello, J.O., D. Abriola, D.E. Alvarez, O.A. Capurro, M. di Tada, A. Etchegoyen, A.M.J. Ferrero, G.V. Martí, A.J. Pacheco, J.E. Testoni and G. Korschinek, Developments of AMS at the TANDAR accelerator 117 (1996) 156
Ferrero, A.M.J., see Fernández Niello, J.O. 117 (1996) 156
Fifield, L.K., R.G. Cresswell, M.L. di Tada, T.R. Ophel, J.P. Day, A.P. Clacher, S.J. King and N.D. Priest, Accelerator mass spectrometry of plutonium isotopes 117 (1996) 295
Fink, D., H.J. Möckel, H. Melzer, R. Klett, F. Hosoi, H. Omichi, L.T. Chadderton and L. Wang, GeV latent ion tracks in sugar; fullerenes and other radiochemical products 117 (1996) 134
Foti, F., see Liritzis, I. 117 (1996) 260
Fuentes, B.E., see Cisneros, C. 117 (1996) 1

Gamaly, E.G., see Chadderton, L.T. 117 (1996) 375
Gao, H., see Asp, S. 117 (1996) 31
García-Santibáñez, F., see Barragán-Vidal, A. 117 (1996) 304
Gartenmann, P., see Haas, P. 117 (1996) 474
Geissel, H., see Schall, I. 117 (1996) 221
Geyer, U., see Qiu, Y. 117 (1996) 151
Gharibyan, V.B., see Aganyants, A.O. 117 (1996) 205
Gießler, K.-H., F. Rauch and N. Fabricius, Glass waveguides produced by ion-exchange A characterization by RBS . 117 (1996) 447
Gigante, G.E., see Zappalà, A. 117 (1996) 145
Glaser, E., see Schulz, R. 117 (1996) 207
Glass Sr., G.A., see St. John, T.J. 117 (1996) 441
Golser, R., see Haas, P. 117 (1996) 474
Goto, T., see Shiomi-Tsuda, N. 117 (1996) 343
Grosswendt, B., see Krajcar Bronić, I. 117 (1996) 5
Guibert, P., see Liritzis, I. 117 (1996) 260

Haas, P., P. Gartenmann, R. Golser, W. Kutschera, M. Suter, H.-A. Synal, M.J.M. Wagner, E. Wild and G. Winkler, Erratum to: "A new half-life measurement of the long-lived fission product ^{126}Sn" [Nucl. Instr. and Meth. B 114 (1996) 131–137] 117 (1996) 474
Hanson, A.L., see Zappalà, A. 117 (1996) 145
Hartmann, J., A. Köniğer, H. Huber, W. Ensinger, W. Assmann, B. Stritzker and B. Rauschenbach, Characterization of high-fluence nitrogen ion implanted pyrolytic graphite 117 (1996) 392
Hashiguchi, Y., see Hayashi, K. 117 (1996) 101
Hautala, M. and I. Koponen, Simulations of submicron-scale erosion and ripple formation on ion bombarded solid surfaces 117 (1996) 95
Hayashi, K., J. Sasaki, O. Ichiko , and Y. Hashiguchi, The effect of additional high dose carbon implantation on the tribological properties of titanium implanted steel 117 (1996) 101
Hesse, E., see Schneider, P. 117 (1996) 77
Hosoi, F., see Fink, D. 117 (1996) 134
Huber, H., see Hartmann, J. 117 (1996) 392
Huggle, D., see Stan-Sion, C. 117 (1996) 26
Hyvönen-Dabek, M., see Kupila-Rantala, T. 117 (1996) 320

Ichikawa, T., see Koizumi, H. 117 (1996) 269
Ichikawa, T., see Koizumi, H. 117 (1996) 431
Ichiko, O., see Hayashi, K. 117 (1996) 101
Imahori, Y., see Cornett, R.J. 117 (1996) 436
Irnich, H., see Schall, I. 117 (1996) 221
Itoh, Y., T. Maeda, T. Nakajima, A. Kitamura, N. Ogiwara and M. Saidoh, Simulation of RBS spectra for a surface with a periodic roughness 117 (1996) 161

Jeon, Y., see Chae, K.H. 117 (1996) 123
Jirovec, J., see Cornett, R.J. 117 (1996) 436
Johnson, W.L., see Qiu, Y. 117 (1996) 151
Jolie, J., see Bertschy, M. 117 (1996) 333
Jones, W.G., see Lally, C.H. 117 (1996) 421
Justiniano, E., see Asp, S. 117 (1996) 31

Kaczanowski, J., Y. Yamamoto, Y. Kido, J. Nakata and K. Takahei, Monte Carlo simulation of channeling spectra for compound crystals with point defects and crystalline precipitates 117 (1996) 275
Kaiser, U., see Schulz, R. 117 (1996) 207
Kalantaryan, O.V., V.T. Kolesnik, S.I. Kononenko, V.I. Muratov and V.E. Storizhko, Luminescence of aluminium induced by fast protons 117 (1996) 68
Kanjilal, D., see Ali, Y.P. 117 (1996) 129
Kanjilal, D., see Arulkumaran, S. 117 (1996) 243
Kankeleit, E., see Schall, I. 117 (1996) 221
Karyukhin, A.N., V.V. Lapin, Yu.M. Protopopov and V.G. Vasil'chenko, Radiation hardness study on molded scintillation tiles and wavelength shifting fibers 117 (1996) 415
Kido, Y., see Kaczanowski, J. 117 (1996) 275
Kim, K.S., Y.W. Kim, N.G. Park, W.S. Cho, D.S. Choi, S.S. Kim and C.N. Whang, Growth mode of Au layer on Si(001) 117 (1996) 289
Kim, S.S., see Kim, K.S. 117 (1996) 289
Kim, Y.W., see Kim, K.S. 117 (1996) 289
King, S.J., see Fifield, L.K. 117 (1996) 295
Kitamura, A., see Itoh, Y. 117 (1996) 161
Klett, R., see Fink, D. 117 (1996) 134
Knapp, J.A., see Pedersen, D. 117 (1996) 170
Koivisto, H., E. Kolehmainen, R. Seppälä, J. Ärje and M. Nurmia, Production of a magnesium ion beam using the MIVOC method 117 (1996) 186
Koizumi, H., T. Ichikawa, H. Yoshida, H. Shibata, S. Tagawa and Y. Yoshida, Radical formation in the radiolysis of solid alanine by protons and helium ions 117 (1996) 269
Koizumi, H., T. Ichikawa, H. Yoshida, H. Namba, M. Taguchi and T. Kojima, Radical formation in the radiolysis of solid alanine by heavy ions 117 (1996) 431
Kojima, T., see Koizumi, H. 117 (1996) 431
Kolehmainen, E., see Koivisto, H. 117 (1996) 186
Kolesnik, V.T., see Kalantaryan, O.V. 117 (1996) 68
Königer, A., see Hartmann, J. 117 (1996) 392
Kononenko, S.I., see Kalantaryan, O.V. 117 (1996) 68
Koponen, I., see Hautala, M. 117 (1996) 95
Kornich, G.V. and G. Betz, Two step simulation of low energy ion beam mixing at different temperatures 117 (1996) 81
Korschinek, G., see Fernández Niello, J.O. 117 (1996) 156
Koslowsky, V.T., see Cornett, R.J. 117 (1996) 436
Kraft, G., see Schall, I. 117 (1996) 221
Kragler, K., see Tomaschko, Ch. 117 (1996) 90
Krajcar Bronić, I. and B. Grosswendt, Ionization yield formation in argon–isobutane mixtures as measured by a proportional-counter method 117 (1996) 5
Kramer, S., see Cornett, R.J. 117 (1996) 436
Kraus, M., see Tomaschko, Ch. 117 (1996) 90
Kreiselmeyer, G., see Tomaschko, Ch. 117 (1996) 90
Krisch, M., see Masciovecchio, C. 117 (1996) 339
Kügler, R., see Tomaschko, Ch. 117 (1996) 199
Kumar, J., see Arulkumaran, S. 117 (1996) 243
Kupila-Rantala, T., M. Hyvönen-Dabek and J.T. Dabek, Optimization of PIXE analysis for Cu and other trace elements in cerebrospinal fluid to improve the detection limits 117 (1996) 320
Kuri, G., Projected range and range straggling of MeV Au ions in Si 117 (1996) 213
Kutschera, W., see Haas, P. 117 (1996) 474

Lagarde, G., see Brissaud, I. 117 (1996) 179
Lally, C.H., G.J. Davies, W.G. Jones and N.J.T. Smith, UV quantum efficiencies of organic fluors 117 (1996) 421
Lapin, V.V., see Karyukhin, A.N. 117 (1996) 415
Le Beyec, Y., see Baudin, K. 117 (1996) 47
LeBeyec, Y., see Tomaschko, Ch. 117 (1996) 90

Lee, Y.S., see Chae, K.H. 117 (1996) 123
Li, G., C. Wang, J. Zhao, Z. Wang and S. Wan, Photoluminescence and activation on SI-GaAs by Si^+ implantation and following rapid thermal annealing 117 (1996) 112
Li Fu-Ming, see Ren Zhong-Min 117 (1996) 249
Lin Jing, see Ren Zhong-Min 117 (1996) 249
Liritzis, I., P. Guibert, F. Foti and M. Schvoerer, Solar bleaching of thermoluminescence of calcites 117 (1996) 260
Lu, M.F., Plasma motion and neutron emission in an 18-kJ plasma focus 117 (1996) 452
Lucarelli, F., see Pio, S. 117 (1996) 311

Macht, M.-P., see Qiu, Y. 117 (1996) 151
Maddalon-Vinante, C., see Erramli, H. 117 (1996) 283
Mäder, M., see Dobler, M. 117 (1996) 117
Maeda, T., see Itoh, Y. 117 (1996) 161
Magel, A., see Schall, I. 117 (1996) 221
Mandò, P.A., see Pio, S. 117 (1996) 311
Manuaba, A., see Pászti, F. 117 (1996) 253
Martí, G.V., see Fernández Niello, J.O. 117 (1996) 156
Martínez, H., see Cisneros, C. 117 (1996) 1
Masciovecchio, C., U. Bergmann, M. Krisch, G. Ruocco, F. Sette and R. Verbeni, A perfect crystal X-ray analyser with 1.5 meV energy resolution 117 (1996) 339
Maurer, F.H.J., see Wästlund, C. 117 (1996) 467
McGuire, J.H., see Corchs, S.E. 117 (1996) 41
Melzer, H., see Fink, D. 117 (1996) 134
Meyer, J.D., see Prigge, U. 117 (1996) 18
Meyer, J.D., see Vollmer, M. 117 (1996) 21
Meyer, O., see Chiang, C.I. 117 (1996) 408
Michelmann, R.W., see Prigge, U. 117 (1996) 18
Michelmann, R.W., see Vollmer, M. 117 (1996) 21
Midy, P., see Brissaud, I. 117 (1996) 179
Milošević, Z., D. Novković and K. Subotić, Energy loss straggling of low energy alpha particles in a medium composed of polyatomic and diatomic molecules 117 (1996) 38
Milton, G.M., see Cornett, R.J. 117 (1996) 436
Milton, J.C.D., see Cornett, R.J. 117 (1996) 436
Misdaq, M.A., see Erramli, H. 117 (1996) 283
Möckel, H.J., see Fink, D. 117 (1996) 134
Mohar, M.F., see Schall, I. 117 (1996) 221
Möller, W., see Dobler, M. 117 (1996) 117
Monakhov, E.V. and A. Nylandsted Larsen, Monte Carlo simulation of α-particle channeling in relaxed SiGe films . 117 (1996) 71
Mondelaers, W., see Bertschy, M. 117 (1996) 333
Montemayor, V.J., see Pedersen, D. 117 (1996) 170
Münzenberg, G., see Schall, I. 117 (1996) 221
Muratov, V.I., see Kalantaryan, O.V. 117 (1996) 68
Murillo, G., see Barragán-Vidal, A. 117 (1996) 304

Nagata, Y., see Shiomi-Tsuda, N. 117 (1996) 343
Nakajima, T., see Itoh, Y. 117 (1996) 161
Nakata, J., see Kaczanowski, J. 117 (1996) 275
Namba, H., see Koizumi, H. 117 (1996) 431
Narsale, A.M., see Ali, Y.P. 117 (1996) 129
Nickel, F., see Schall, I. 117 (1996) 221
Nolte, E., see Stan-Sion, C. 117 (1996) 26
Novković, D., see Milošević, Z. 117 (1996) 38
Nurmia, M., see Koivisto, H. 117 (1996) 186
Nylandsted Larsen, A., see Monakhov, E.V. 117 (1996) 71

Ogawa, H., see Shiomi-Tsuda, N. 117 (1996) 343
Ogiwara, N., see Itoh, Y. 117 (1996) 161
Ojo, J.O., A.F. Oluwole, M.A. Durosinmi and O.I. Asubiojo, Regulation of elemental ratios in affective disorders: A study using PIXE 117 (1996) 175
Oluwole, A.F., see Ojo, J.O. 117 (1996) 175
Omichi, H., see Fink, D. 117 (1996) 134
Ophel, T.R., see Fifield, L.K. 117 (1996) 295
Othonos, A. and C. Christofides, Multi-wavelength Raman probing of phosphorus implanted silicon wafers 117 (1996) 367

Pacheco, A.J., see Fernández Niello, J.O. 117 (1996) 156
Padhi, H.C., see Dhal, B.B. 117 (1996) 218
Parilis, E.S., see Baudin, K. 117 (1996) 47
Park, N.G., see Kim, K.S. 117 (1996) 289
Pászti, F., A. Manuaba, E. Szilágyi, É. Vázsonyi and Z. Vértesy, Densification and noble gas retention of ion-implanted porous silicon 117 (1996) 253
Pedersen, D., R.A. Weller, M.R. Weller, V.J. Montemayor, J.C. Banks and J.A. Knapp, Sputtering and migration of trace quantities of transition metal atoms on silicon 117 (1996) 170
Percolla, R., see Torrisi, L. 117 (1996) 387
Pfaffenlehner, M., see Benka, O. 117 (1996) 350
Pio, S., P. Prati, A. Zucchiatti, F. Lucarelli, P.A. Mandò and C. Varaldo, Provenance study of Ligurian pottery by PIXE analysis 117 (1996) 311
Prati, P., see Pio, S. 117 (1996) 311
Priest, N.D., see Fifield, L.K. 117 (1996) 295
Prigge, U., J.D. Meyer, R.W. Michelmann and K. Bethge, Investigation of the reaction $^{15}N(\alpha,n)^{18}F$ for materials analysis 117 (1996) 18
Protopopov, Yu.M., see Karyukhin, A.N. 117 (1996) 415

Qiu, Y., U. Geyer, S. Schneider, M.-P. Macht, W.L. Johnson and T.A. Tombrello, Investigation of beryllium diffusion in the supercooled liquid and glassy states of the amorphous alloy $Zr_{41.2}Ti_{13.8}Cu_{12.5}Ni_{10}Be_{22.5}$ by high energy helium elastic backscattering 117 (1996) 151

Rauch, F., see Gießler, K.-H. 117 (1996) 447
Rauschenbach, B., see Hartmann, J. 117 (1996) 392
Ren Yun-Zhu, see Ren Zhong-Min 117 (1996) 249
Ren Zhong-Min, Du Yuan-Cheng, Ying Zhi-Feng, Li Fu-Ming, Lin Jing, Ren Yun-Zhu and Zong Xiang-Fu, Characterization of carbon nitride films modified by low energy ion-beam bombardment 117 (1996) 249
Reuther, H., see Dobler, M. 117 (1996) 117
Rivarola, R.D., see Corchs, S.E. 117 (1996) 41
Ruocco, G., see Masciovecchio, C. 117 (1996) 339

Saemann-Ischenko, G., see Tomaschko, Ch. 117 (1996) 90
Saidoh, M., see Itoh, Y. 117 (1996) 161
Sakamoto, N., see Shiomi-Tsuda, N. 117 (1996) 343
Salvi, V.P., see Ali, Y.P. 117 (1996) 129
Sasaki, J., see Hayashi, K. 117 (1996) 101
Schall, I., D. Schardt, H. Geissel, H. Irnich, E. Kankeleit, G. Kraft, A. Magel, M.F. Mohar, G. Münzenberg, F. Nickel, C. Scheidenberger and W. Schwab, Charge-changing nuclear reactions of relativistic light-ion beams ($5 \leq Z \leq 10$) passing through thick absorbers 117 (1996) 221
Schardt, D., see Schall, I. 117 (1996) 221
Scheidenberger, C., see Schall, I. 117 (1996) 221
Schinner, A., see Benka, O. 117 (1996) 350
Schneider, P., L. Bischoff, J. Teichert and E. Hesse, Focused ion beam sputtering yield measurements for cobalt ions on silicon and related materials 117 (1996) 77
Schneider, S., see Qiu, Y. 117 (1996) 151
Schoppmann, Ch., see Tomaschko, Ch. 117 (1996) 90
Schuch, R., see Asp, S. 117 (1996) 31
Schulz, R., T. Bachmann, U. Kaiser and E. Glaser, Optimum temperature for ion beam induced crystallization of GaAs 117 (1996) 207
Schurr, M., see Tomaschko, Ch. 117 (1996) 199
Schvoerer, M., see Liritzis, I. 117 (1996) 260
Schwab, W., see Schall, I. 117 (1996) 221
Seppälä, R., see Koivisto, H. 117 (1996) 186
Sette, F., see Masciovecchio, C. 117 (1996) 339
Shah, A.P., see Ali, Y.P. 117 (1996) 129
Sheu, W.J., see St. John, T.J. 117 (1996) 441
Shibata, H., see Koizumi, H. 117 (1996) 269
Shiomi-Tsuda, N., N. Sakamoto, H. Ogawa, M. Tanaka, T. Goto and Y. Nagata, Stopping powers of havar for protons from 4.0 to 13.0 MeV 117 (1996) 343
Silenko, A.Ya., see Stepanov, S.A. 117 (1996) 55
Smith, N.J.T., see Lally, C.H. 117 (1996) 421

Stan-Sion, C., D. Huggle, E. Nolte, A. Blinov and M. Dumitru, AMS measurements of the production cross sections of ^{36}Cl with protons up to 1 GeV 117 (1996) 26
Stepanov, S.A., A.Ya. Silenko, A.P. Ulyanenkov and I.Ya. Dubovskaya, Multi-wave parametric X-ray production by relativistic particles in crystals: comparison of computations and experimental results 117 (1996) 55
St. John, T.J., W.J. Sheu and G.A. Glass Sr., Surface oxygen implanted in titanium by recoil collisions with 1 MeV gold ions 117 (1996) 441
Storizhko, V.E., see Kalantaryan, O.V. 117 (1996) 68
Stritzker, B., see Hartmann, J. 117 (1996) 392
Subotić, K., see Milošević, Z. 117 (1996) 38
Suter, M., see Haas, P. 117 (1996) 474
Swart, J.W., see de Souza, J.P. 117 (1996) 403
Synal, H.-A., see Haas, P. 117 (1996) 474
Szilágyi, E., see Pászti, F. 117 (1996) 253

Tagawa, S., see Koizumi, H. 117 (1996) 269
Taguchi, M., see Koizumi, H. 117 (1996) 431
Takahei, K., see Kaczanowski, J. 117 (1996) 275
Tanaka, M., see Shiomi-Tsuda, N. 117 (1996) 343
Tartari, A., C. Bonifazzi, J. Felsteiner and E. Casnati, Detailed multiple-scattering profile evaluations in collimated photon scattering techniques 117 (1996) 325
Teichert, J., see Schneider, P. 117 (1996) 77
Testoni, J.E., see Fernández Niello, J.O. 117 (1996) 156
Tomaschko, Ch., Ch. Schoppmann, M. Kraus, K. Kragler, G. Kreiselmeyer, G. Saemann-Ischenko, H. Voit, A. Brunelle, S. Della-Negra and Y. LeBeyec, MeV cluster ion induced defect production in high T_c superconductors 117 (1996) 90
Tomaschko, Ch., R. Kügler, M. Schurr and H. Voit, MeV cluster ions from the Erlangen tandem accelerator 117 (1996) 199
Tombrello, T.A., see Qiu, Y. 117 (1996) 151
Torrisi, L. and R. Percolla, Ion beam processing of polyvinylidene fluoride 117 (1996) 387
Trautmann, D., see Dhal, B.B. 117 (1996) 218
Tripathi, R.K., F.A. Cucinotta and J.W. Wilson, Accurate universal parameterization of absorption cross sections. . . 117 (1996) 347

Udhayasankar, M., see Arulkumaran, S. 117 (1996) 243
Ulyanenkov, A.P., see Stepanov, S.A. 117 (1996) 55
Urbassek, H.M., see Colla, T.J. 117 (1996) 361
Uyttenhove, J., see Everaert, J.L. 117 (1996) 397

Van Meirhaeghe, R.L., see Everaert, J.L. 117 (1996) 397
Varaldo, C., see Pio, S. 117 (1996) 311
Vartanov, Yu.A., see Aganyants, A.O. 117 (1996) 205
Vasil'chenko, V.G., see Karyukhin, A.N. 117 (1996) 415
Vázsonyi, É., see Pászti, F. 117 (1996) 253
Verbeni, R., see Masciovecchio, C. 117 (1996) 339
Verhaegen, F., see Everaert, J.L. 117 (1996) 397
Vértesy, Z., see Pászti, F. 117 (1996) 253
Voit, H., see Tomaschko, Ch. 117 (1996) 90
Voit, H., see Tomaschko, Ch. 117 (1996) 199
Vojtyla, P., Fast computer simulations of background of low-level Ge γ-spectrometers induced by ^{210}Pb/^{210}Bi in shielding lead 117 (1996) 189
Vollmer, M., J.D. Meyer, R.W. Michelmann and K. Bethge, Boron detection using the nuclear reaction ^{11}B(p, α)2α . 117 (1996) 21

Wagner, M.J.M., see Haas, P. 117 (1996) 474
Wan, S., see Li, G. 117 (1996) 112
Wang, C., see Li, G. 117 (1996) 112
Wang, L., see Fink, D. 117 (1996) 134
Wang, T.M., see Wang, W.J. 117 (1996) 140
Wang, W.J., T.M. Wang and B.L. Chen, Hydrogen release from diamondlike carbon films due to thermal annealing in vacuum 117 (1996) 140
Wang, Z., see Li, G. 117 (1996) 112
Wästlund, C. and F.H.J. Maurer, Positron lifetime distributions in polymers determined with the maximum entropy method 117 (1996) 467
Weller, M.R., see Pedersen, D. 117 (1996) 170
Weller, R.A., see Pedersen, D. 117 (1996) 170

Whang, C.N., see Chae, K.H. 117 (1996) 123
Whang, C.N., see Kim, K.S. 117 (1996) 289
Wild, E., see Haas, P. 117 (1996) 474
Wilson, J.W., see Tripathi, R.K. 117 (1996) 347
Winkler, G., see Haas, P. 117 (1996) 474

Yamamoto, Y., see Kaczanowski, J. 117 (1996) 275
Ying Zhi-Feng, see Ren Zhong-Min 117 (1996) 249
Yoshida, H., see Koizumi, H. 117 (1996) 269
Yoshida, H., see Koizumi, H. 117 (1996) 431
Yoshida, Y., see Koizumi, H. 117 (1996) 269

Zappalà, A., S. Bajt, G.E. Gigante and A.L. Hanson, Applications of EDXRF in the conservation of acid papers using a synchrotron light microbeam 117 (1996) 145
Zhao, J., see Li, G. 117 (1996) 112
Zong, W., see Asp, S. 117 (1996) 31
Zong Xiang-Fu, see Ren Zhong-Min 117 (1996) 249
Zucchiatti, A., see Pio, S. 117 (1996) 311

ELSEVIER

Nuclear Instruments and Methods in Physics Research B 117 (1996) 485–487

NIM B
Beam Interactions with Materials & Atoms

Subject index

Basic Data for Materials Modification and Analysis

Single electron capture of H^+ in Mg in the energy range 0.5 to 5.0 keV, C. Cisneros, H. Martínez, B.E. Fuentes, I. Alvarez, J. de Urquijo and I. Dominguez 117 (1996) 1
Ionization yield formation in argon–isobutane mixtures as measured by a proportional-counter method, I. Krajcar Bronić and B. Grosswendt 117 (1996) 5
Investigation of the reaction $^{15}N(\alpha,n)^{18}F$ for materials analysis, U. Prigge, J.D. Meyer, R.W. Michelmann and K. Bethge 117 (1996) 18
Boron detection using the nuclear reaction $^{11}B(p,\alpha)2\alpha$, M. Vollmer, J.D. Meyer, R.W. Michelmann and K. Bethge . 117 (1996) 21
AMS measurements of the production cross sections of ^{36}Cl with protons up to 1 GeV, C. Stan-Sion, D. Huggle, E. Nolte, A. Blinov and M. Dumitru 117 (1996) 26
Laser-induced recombination of D^+, S. Asp, R. Schuch, D.R. DeWitt, C. Biedermann, H. Gao, W. Zong, G. Andler and E. Justiniano 117 (1996) 31
Energy loss straggling of low energy alpha particles in a medium composed of polyatomic and diatomic molecules, Z. Milošević, D. Novković and K. Subotić 117 (1996) 38
Interference effects in collisions between heavy ions and molecular targets, S.E. Corchs, H.F. Busnengo, R.D. Rivarola and J.H. McGuire. 117 (1996) 41
Projected range and range straggling of MeV Au ions in Si, G. Kuri. 117 (1996) 213
A strange projectile dependence of L_2-subshell ionization cross section of Au for ^{28}Si and ^{32}S ion bombardment, B.B. Dhal, H.C. Padhi and D. Trautmann 117 (1996) 218
Charge-changing nuclear reactions of relativistic light-ion beams ($5 \leq Z \leq 10$) passing through thick absorbers, I. Schall, D. Schardt, H. Geissel, H. Irnich, E. Kankeleit, G. Kraft, A. Magel, M.F. Mohar, G. Münzenberg, F. Nickel, C. Scheidenberger and W. Schwab 117 (1996) 221
Stopping powers of havar for protons from 4.0 to 13.0 MeV, N. Shiomi-Tsuda, N. Sakamoto, H. Ogawa, M. Tanaka, T. Goto and Y. Nagata 117 (1996) 343
Accurate universal parameterization of absorption cross sections, R.K. Tripathi, F.A. Cucinotta and J.W. Wilson. . . . 117 (1996) 347

Atomic Collisions in Solids

Sublinear effect in electron emission from solids bombarded with swift gold clusters, K. Baudin, A. Brunelle, S. Della-Negra, J. Depauw, Y. Le Beyec and E.S. Parilis 117 (1996) 47
Multi-wave parametric X-ray production by relativistic particles in crystals: comparison of computations and experimental results, S.A. Stepanov, A.Ya. Silenko, A.P. Ulyanenkov and I.Ya. Dubovskaya 117 (1996) 55
Luminescence of aluminium induced by fast protons, O.V. Kalantaryan, V.T. Kolesnik, S.I. Kononenko, V.I. Muratov and V.E. Storizhko 117 (1996) 68
Monte Carlo simulation of α-particle channeling in relaxed SiGe films, E.V. Monakhov and A. Nylandsted Larsen . . 117 (1996) 71
Focused ion beam sputtering yield measurements for cobalt ions on silicon and related materials, P. Schneider, L. Bischoff, J. Teichert and E. Hesse 117 (1996) 77
Two step simulation of low energy ion beam mixing at different temperatures, G.V. Kornich and G. Betz 117 (1996) 81
MeV cluster ion induced defect production in high T_c superconductors, Ch. Tomaschko, Ch. Schoppmann, M. Kraus, K. Kragler, G. Kreiselmeyer, G. Saemann-Ischenko, H. Voit, A. Brunelle, S. Della-Negra and Y. LeBeyec. 117 (1996) 90
Energy distributions of hydrocarbon secondary ions from thin organic films under keV ion bombardment: Correlation between kinetic and formation energy of ions sputtered from tricosenoic acid, A. Delcorte and P. Bertrand 117 (1996) 235
Electron emission yield of Al, Cu and Au targets induced by fast hydrogen and helium ions, O. Benka, M. Pfaffenlehner and A. Schinner 117 (1996) 350
Computer simulation of the energy loss spectra in bent crystals, V. Biryukov 117 (1996) 357
Influence of adatom coverage on sputter yield, T.J. Colla and H.M. Urbassek. 117 (1996) 361

Ion Beam Modification of Materials

Simulations of submicron-scale erosion and ripple formation on ion bombarded solid surfaces, M. Hautala and I. Koponen 117 (1996) 95

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The effect of additional high dose carbon implantation on the tribological properties of titanium implanted steel, K. Hayashi, J. Sasaki, O. Ichiko, and Y. Hashiguchi 117 (1996) 101
Photoluminescence and activation on SI-GaAs by Si^+ implantation and following rapid thermal annealing, G. Li, C. Wang, J. Zhao, Z. Wang and S. Wan 117 (1996) 112
Investigations of ion implanted iron silicide layers after annealing and irradiation, M. Dobler, H. Reuther, M. Betzl, M. Mäder and W. Möller 117 (1996) 117
Charge redistribution in ion-beam-mixed Pd–Ag alloys, K.H. Chae, Y.S. Lee, C.N. Whang, Y. Jeon, B.S. Choi and M. Croft 117 (1996) 123
Electrical characteristics of GaAs implanted with 70 MeV ^{120}Sn ions, Y.P. Ali, A.M. Narsale, U. Bhambhani, A. Damle, V.P. Salvi, B.M. Arora, A.P. Shah and D. Kanjilal 117 (1996) 129
Optimum temperature for ion beam induced crystallization of GaAs, R. Schulz, T. Bachmann, U. Kaiser and E. Glaser 117 (1996) 207
Electrical characteristics of 100 MeV ^{28}Si implanted LEC grown GaAs⟨100⟩, S. Arulkumaran, J. Arokiaraj, M. Udhayasankar, J. Kumar and D. Kanjilal 117 (1996) 243
Characterization of carbon nitride films modified by low energy ion-beam bombardment, Ren Zhong-Min, Du Yuan-Cheng, Ying Zhi-Feng, Li Fu-Ming, Lin Jing, Ren Yun-Zhu and Zong Xiang-Fu 117 (1996) 249
Densification and noble gas retention of ion-implanted porous silicon, F. Pászti, A. Manuaba, E. Szilágyi, É. Vázsonyi and Z. Vértesy 117 (1996) 253
Multi-wavelength Raman probing of phosphorus implanted silicon wafers, A. Othonos and C. Christofides 117 (1996) 367
Fullerene genesis by ion beams II: Disclinations and the corranulene road, L.T. Chadderton and E.G. Gamaly 117 (1996) 375
Ion beam processing of polyvinylidene fluoride, L. Torrisi and R. Percolla 117 (1996) 387
Characterization of high-fluence nitrogen ion implanted pyrolytic graphite, J. Hartmann, A. Königer, H. Huber, W. Ensinger, W. Assmann, B. Stritzker and B. Rauschenbach 117 (1996) 392
Quantitative prediction of acceptor concentration reduction in boron doped silicon due to electron irradiation, J.L. Everaert, F. Verhaegen, R.L. Van Meirhaeghe, J. Uyttenhove and F. Cardon 117 (1996) 397
Rapid thermal annealing of Mg^+ and P^+ co-implanted GaAs, J.P. de Souza, H. Boudinov and J.W. Swart 117 (1996) 403
The modification of mechanical properties and adhesion of boron carbide sputtered films by ion implantation, C.I. Chiang, O. Meyer and R.M.C. da Silva 117 (1996) 408

Effects of Radiation

GeV latent ion tracks in sugar; fullerenes and other radiochemical products, D. Fink, H.J. Möckel, H. Melzer, R. Klett, F. Hosoi, H. Omichi, L.T. Chadderton and L. Wang 117 (1996) 134
Solar bleaching of thermoluminescence of calcites, I. Liritzis, P. Guibert, F. Foti and M. Schvoerer 117 (1996) 260
Radical formation in the radiolysis of solid alanine by protons and helium ions, H. Koizumi, T. Ichikawa, H. Yoshida, H. Shibata, S. Tagawa and Y. Yoshida 117 (1996) 269
Radiation hardness study on molded scintillation tiles and wavelength shifting fibers, A.N. Karyukhin, V.V. Lapin, Yu.M. Protopopov and V.G. Vasil'chenko 117 (1996) 415
UV quantum efficiencies of organic fluors, C.H. Lally, G.J. Davies, W.G. Jones and N.J.T. Smith 117 (1996) 421
Measurement of supralinearity factor of CaF_2 : Tm (TLD-300) thermoluminescent dosimeter, M. Angelone, M. Chiti and A. Esposito 117 (1996) 428
Radical formation in the radiolysis of solid alanine by heavy ions, H. Koizumi, T. Ichikawa, H. Yoshida, H. Namba, M. Taguchi and T. Kojima 117 (1996) 431

Analysis of Materials

Hydrogen release from diamondlike carbon films due to thermal annealing in vacuum, W.J. Wang, T.M. Wang and B.L. Chen 117 (1996) 140
Applications of EDXRF in the conservation of acid papers using a synchrotron light microbeam, A. Zappalà, S. Bajt, G.E. Gigante and A.L. Hanson 117 (1996) 145
Investigation of beryllium diffusion in the supercooled liquid and glassy states of the amorphous alloy $Zr_{41.2}Ti_{13.8}Cu_{12.5}Ni_{10}Be_{22.5}$ by high energy helium elastic backscattering, Y. Qiu, U. Geyer, S. Schneider, M.-P. Macht, W.L. Johnson and T.A. Tombrello 117 (1996) 151
Developments of AMS at the TANDAR accelerator, J.O. Fernández Niello, D. Abriola, D.E. Alvarez, O.A. Capurro, M. di Tada, A. Etchegoyen, A.M.J. Ferrero, G.V. Martí, A.J. Pacheco, J.E. Testoni and G. Korschinek 117 (1996) 156
Simulation of RBS spectra for a surface with a periodic roughness, Y. Itoh, T. Maeda, T. Nakajima, A. Kitamura, N. Ogiwara and M. Saidoh 117 (1996) 161
Sputtering and migration of trace quantities of transition metal atoms on silicon, D. Pedersen, R.A. Weller, M.R. Weller, V.J. Montemayor, J.C. Banks and J.A. Knapp 117 (1996) 170
Regulation of elemental ratios in affective disorders: A study using PIXE, J.O. Ojo, A.F. Oluwole, M.A. Durosinmi and O.I. Asubiojo 117 (1996) 175

Study of multilayers by PIXE technique. Application to paintings, I. Brissaud, G. Lagarde and P. Midy 117 (1996) 179
Monte Carlo simulation of channeling spectra for compound crystals with point defects and crystalline precipitates, J. Kaczanowski, Y. Yamamoto, Y. Kido, J. Nakata and K. Takahei 117 (1996) 275
Study of the oxygen behaviour in thermally treated Czochralski silicon by combining CPAA with ion channeling, H. Erramli, M.A. Misdaq, G. Blondiaux, C. Maddalon-Vinante and D. Barbier 117 (1996) 283
Growth mode of Au layer on Si(001), K.S. Kim, Y.W. Kim, N.G. Park, W.S. Cho, D.S. Choi, S.S. Kim and C.N. Whang 117 (1996) 289
Accelerator mass spectrometry of plutonium isotopes, L.K. Fifield, R.G. Cresswell, M.L. di Tada, T.R. Ophel, J.P. Day, A.P. Clacher, S.J. King and N.D. Priest 117 (1996) 295
Analysis of a very rough sample by accelerator techniques, A. Barragán-Vidal, F. García-Santibáñez, G. Murillo, E. Andrade I. and M. Feregrino-Dorantes 117 (1996) 304
Provenance study of Ligurian pottery by PIXE analysis, S. Pio, P. Prati, A. Zucchiatti, F. Lucarelli, P.A. Mandò and C. Varaldo 117 (1996) 311
Optimization of PIXE analysis for Cu and other trace elements in cerebrospinal fluid to improve the detection limits, T. Kupila-Rantala, M. Hyvönen-Dabek and J.T. Dabek 117 (1996) 320
High temperature pyrolysis to extract ^{36}Cl for Accelerator Mass Spectrometry measurements, R.J. Cornett, H.R. Andrews, L. Chant, T. Chaput, Y. Imahori, J. Jirovec, S. Kramer, V.T. Koslowsky, G.M. Milton and J.C.D. Milton 117 (1996) 436
Surface oxygen implanted in titanium by recoil collisions with 1 MeV gold ions, T.J. St. John, W.J. Sheu and G.A. Glass Sr. 117 (1996) 441
Glass waveguides produced by ion-exchange A characterization by RBS, K.-H. Gießler, F. Rauch and N. Fabricius . . 117 (1996) 447
Erratum to: "A new half-life measurement of the long-lived fission product ^{126}Sn" [Nucl. Instr. and Meth. B 114 (1996) 131–137], P. Haas, P. Gartenmann, R. Golser, W. Kutschera, M. Suter, H.-A. Synal, M.J.M. Wagner, E. Wild and G. Winkler 117 (1996) 474

Ion Sources and Beam Optics

Production of a magnesium ion beam using the MIVOC method, H. Koivisto, E. Kolehmainen, R. Seppälä, J. Ärje and M. Nurmia 117 (1996) 186

Experimental Methods and Equipment

Fast computer simulations of background of low-level Ge γ-spectrometers induced by $^{210}Pb/^{210}Bi$ in shielding lead, P. Vojtyla 117 (1996) 189
MeV cluster ions from the Erlangen tandem accelerator, Ch. Tomaschko, R. Kügler, M. Schurr and H. Voit 117 (1996) 199
Polarization of photon and electron beams by means of an oriented monocyrstal, A.O. Aganyants, V.B. Gharibyan and Yu.A. Vartanov 117 (1996) 205
Detailed multiple-scattering profile evaluations in collimated photon scattering techniques, A. Tartari, C. Bonifazzi, J. Felsteiner and E. Casnati 117 (1996) 325
A tunable monochromatic gamma-ray source. Part 4. The FCMT operation mode, M. Bertschy, J. Jolie and W. Mondelaers 117 (1996) 333
A perfect crystal X-ray analyser with 1.5 meV energy resolution, C. Masciovecchio, U. Bergmann, M. Krisch, G. Ruocco, F. Sette and R. Verbeni (*Letter to the Editor*) 117 (1996) 339
Plasma motion and neutron emission in an 18-kJ plasma focus, M.F. Lu 117 (1996) 452
A new iterative method for deconvolution of Doppler broadened lineshapes of positron annihilation γ-ray spectra, L. Calderin and J.J. Diaz 117 (1996) 457
Optimization of crystal extraction experiment, V. Biryukov 117 (1996) 463
Positron lifetime distributions in polymers determined with the maximum entropy method, C. Wästlund and F.H.J. Maurer 117 (1996) 467

Letters to the Editor

Optimum temperature for ion beam induced crystallization of GaAs, R. Schulz, T. Bachmann, U. Kaiser and E. Glaser 117 (1996) 207
A perfect crystal X-ray analyser with 1.5 meV energy resolution, C. Masciovecchio, U. Bergmann, M. Krisch, G. Ruocco, F. Sette and R. Verbeni 117 (1996) 339

Errata

Erratum to: "A new half-life measurement of the long-lived fission product ^{126}Sn" [Nucl. Instr. and Meth. B 114 (1996) 131–137], P. Haas, P. Gartenmann, R. Golser, W. Kutschera, M. Suter, H.-A. Synal, M.J.M. Wagner, E. Wild and G. Winkler 117 (1996) 474

(continued from page 4 of cover)

Surface oxygen implanted in titanium by recoil collisions with 1 MeV gold ions
T.J. St. John, W.J. Sheu and G.A. Glass Sr. . 441

Glass waveguides produced by ion-exchange A characterization by RBS
K.-H. Gießler, F. Rauch and N. Fabricius . . . 447

Experimental Methods and Equipment

Plasma motion and neutron emission in an 18-kJ plasma focus
M.F. Lu 452

A new iterative method for deconvolution of Doppler broadened lineshapes of positron annihilation γ-ray spectra
L. Calderin and J.J. Diaz 457

Optimization of crystal extraction experiment
V. Biryukov 463

Positron lifetime distributions in polymers determined with the maximum entropy method
C. Wästlund and F.H.J. Maurer 467

Errata

Erratum to: "A new half-life measurement of the long-lived fission product ^{126}Sn" [Nucl. Instr. and Meth. B 114 (1996) 131–137]
P. Haas, P. Gartenmann, R. Golser, W. Kutschera, M. Suter, H.-A. Synal, M.J.M. Wagner, E. Wild and G. Winkler 474

Calendar 475
Author index 477
Subject index 485